Notice of References Cited Application/Control No. | Applicant(s)/Patent Under Reexamination NANAI ET AL. Examiner | Art Unit | Page 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
*	Α	US-2004/0201015	10-2004	Ong et al.	257/040
*	В	US-2003/0226996	12-2003	Aramaki et al.	252/62.30Q
*	O	US-5,349,203	09-1994	Hanazato et al.	257/40
*	D	US-5,525,811	06-1996	Sakurai et al.	257/40
	Е	US-			
	F	US-			
	G	US-			
	Ι	US-			
	-	US-			
	J	US-			
	K	US-			
	L	US-			
	М	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	0					
	Р					
	Ø					
	R					
	Ø					
	Т					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)		
	U	Xiao, K., et al. "Influence of the Substrate Temperature During Deposition on Film Characteristics of Copper Phthalocyanine and Field-Effect Transistor Properties." APPL. PHYS. A: MATER. SCI. PROC., Vol. 77 (2003): pp. 367-370.		
	\ \	Horowitz, G., et al. "Field-Effect Transistor Made with a Sexithiophene Single Crystal." ADV. MATER., Vol. 8 (1996): pp. 52-54.		
	w	Horowitz, G., et al. "Growth and Characterization of Sexithiophene Single Crystals." CHEM. MATER., Vol. 7 (1995): pp. 1337-1341.		
	х	Bao, Z., et al. "Organic Field-Effect Transistors with High Mobility Based on Copper Phthalocyanine." APPL. PHYS. LETT., Vol. 69 (1996): pp. 3066-3068.		

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).) Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.